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January 20177

FUSB252 Type-C CC with High Speed Digital (HSD) Port Protection Switch

Features

- Fully Type-C Port Protection
- Supports USB Type-CTM Specification 1.2
- V_{CC} 0 V- 5.5 V
- 20 V DC Protection on V_{CC}
- 16 V DC protection on HSD Port
- V_{DD} Operating Range, 2.7 V- 5.5 V
- Current Capability: 1 A
- CC R_{ON}: 0.3 Ω Typical
- HSD R_{ON}: 5 Ω Typical
- Wide -3 db Bandwidth: 1 GHz
- Low Power Operation: I_{CC} = 9 µA Typical
- Dead Battery Support (UFP Support when No Power Applied)
- CC Over-Voltage Protection: Typical = 5.6 V

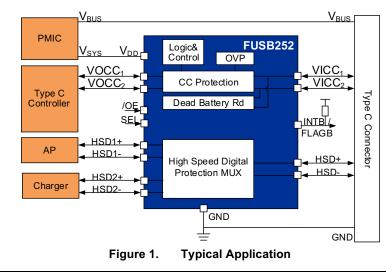
Description

The FUSB252 is an integrated port protection switch for USB Type-C applications. This product will protect HSD+/- and CCx pins when stressed with voltages up to 20 V. Over-Voltage Protection (OVP) at 5.8 V typical will protect the system for Electrical Overstress (EOS) damage. With a fully integrated USB 2.0 switch for HSD+/-, this product can be easily integrated into existing solutions. The HSD switches can pass USB 2.0 signals with bandwidth 1 GHz to maintain signal integrity and eye compliance.

The CC switches have very low R_{ON} of 0.3 Ω to minimize signal attenuation. The FUSB252 also provides Dead Battery support per the Type-C specification Additional features include Under-Voltage Lockout (UVLO) and thermal shutdown.

Applications

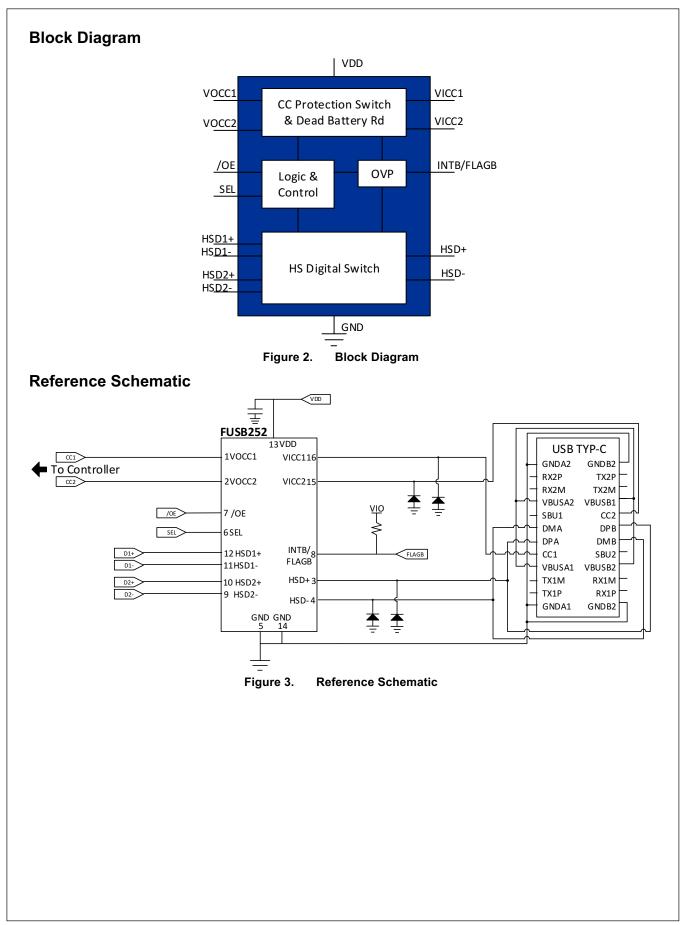
- Smartphones
- Tablets
- Laptops



Ordering Information

| Part Number | Operating Temperature Range | Package | Package Packing Method | |
|-------------|--------------------------------|--|------------------------|----|
| FUSB252UMX | -40 to 85°C | 16-Lead Ultrathin Molded Leadless Package (UMLP) 1.8 x 2.6 mm | Tape and Reel | UZ |

USB Type- C^{TM} is a trademark of USB Implementers Forum, Inc.



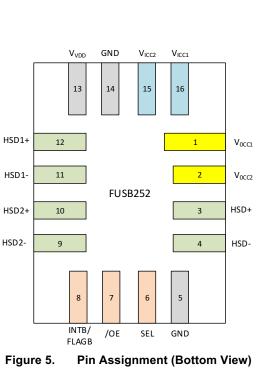


Figure 5.

GND SEL Figure 4. Pin Assignment (Top Through View)

Pin Descriptions

Pin Configuration

V_{0CC1}

V_{0CC2}

HSD+

HSD-

 V_{ICC1}

16

1

3

4

5

6

7

/OE

V_{ICC2}

15

FUSB252

GND

14

 V_{VDD}

13

12

11

10

9

8

INTB/

FLAG B

HSD1+

HSD1-

HSD2+

HSD2-

| Bump | Name | Туре | Description |
|----------------|------------------|--------------|--|
| Power Interfa | ice | | |
| 13 | VDD | Power | Power |
| 5,14 | GND | Ground | Ground |
| USB Type-C | Connector Inter | rface Input | |
| 15, 16 | VICC1,2 | Input | Type C CC Interface OVP protection input, Connect to connector |
| USB Type-C | Connector Inter | rface Output | |
| 1, 2 | VOCC1,2 | Output | Type C CC Interface output. Connect to controller |
| USB High Sp | eed Data Interfa | ace | |
| 3 | HSD+ | I/O | Common High Speed Digital / USB Data Bus |
| 4 | HSD- | I/O | Common High Speed Digital / USB Data Bus |
| 12 | HSD1+ | I/O | Multiplexed Source Input 1 |
| 11 | HSD1- | I/O | Multiplexed Source Input 1 |
| 10 | HSD2+ | I/O | Multiplexed Source Input 2 |
| 9 | HSD2- | I/O | Multiplexed Source Input 2 |
| Signal Interfa | ice | | |
| 7 | /OE | I/O | Switch Enable |
| 6 | SEL | I/O | Switch Select |
| 8 | INTB/FLAGB | Output | OVP Interrupt Flag |

FUSB252 — Type C CC with D+\D- Port Protection Switch

Table 1. CC Switch Truth Table Configuration

| V _{DD} | V _{ICC} Voltage | CC Switch Configuration |
|------------------------|--------------------------|------------------------------|
| | 0 V – 5.8 V | OFF Dead Battery Rd Inserted |
| 0 V - UVLO (Not Valid) | 5.8 V to 20 V | OFF Dead Battery Rd Inserted |
| | 0 V – 5.8 V | On |
| 2.7 V – 5.5 V (Valid) | 5.8 V to 20 V | OFF (OVP) |

Table 2. Device Truth Table Configuration

| /OE | SEL | VDD | HSD+/HSD- | CC |
|-----|-----|-----------|-------------------------|--------------|
| 1 | 0 | Not Valid | X (Open/High-Z) | Dead Battery |
| 0 | 0 | Not Valid | X (Open/High-Z) Dead Ba | |
| 1 | Х | Valid | X (Open/High-Z) | On |
| 0 | 0 | Valid | HSD1+/HSD1- | On |
| 0 | 1 | Valid | HSD2+/HSD2- | On |

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

| Symbol | Parameter | | | Min. | Max. | Unit |
|--|---|--|---------|--|------|------|
| V_{VDD} | Supply Voltage from V _{DD} | | | -0.5 | 12.0 | V |
| V _{VICC} | V _{ICCx} , to GND | | | -0.5 | 24 | V |
| V _{SW} | V _{HSD±} , to GND | Itage from V _{DD} ND ND ND yth to GND Voltage (S, /OE) vitch Current Current Diode Current Diode Current Diode Current Diode Current Diode Current Diode Current Connector Pins Junction Temperature perature (Soldering, 10 seconds) -4-2 System ESD VICCx to GND -4-5 Surge ESD VICCx to GND VHSD± to GND Power to GND External Pins to GND VHSD±, VICCx) System Side Pin (VHSD±, VICCx), S, /OE, | | | | V |
| $V_{\text{OCC},}V_{\text{SW}}$ | V _{OCCx} V _{HSDx+/-} to GND | tage from V _{DD} ND ND ND ND Voltage (S, /OE) Voltage (S, /OE) Vitch Current Current Current Diode Current Diode Current Curren | | | | V |
| VCONTROL | DC Input Voltage (S, /OE) | age from V _{DD} ND ND x+/- to GND oltage (S, /OE) tch Current Current iode Current mperature Range lunction Temperature erature (Soldering, 10 seconds) 4-2 System ESD Viccx, VHSD±, 0 Viccx to GND Viscb dy Model, JEDEC JESD22-A114 August Model, JEDEC JESD22-A114 | | | | V |
| Iccsw | DC CC Switch Current | $\frac{\text{Connector Pins}}{(V_{VDD}, V_{ICCx}, V_{HSD\pm,})} \xrightarrow[]{Ai}{C}$ $\frac{V_{ICCx} \text{ to GND}}{V_{HSD\pm} \text{ to GND}}$ $\frac{V_{ICCx} \text{ to GND}}{V_{HSD\pm} \text{ to GND}}$ Power to GND $\frac{\text{External Pins to GND}}{(V_{HSD\pm}, V_{ICCx})}$ System Side Pin $(V_{HSD\pm,} V_{OCCx}, S, /OE, FLAGB)$ | | | 1.25 | Α |
| IUSBSW | DC Output Current | | | | 100 | mA |
| I _{IK} | DC Input Diode Current | | | | | mA |
| TSTORAGE | Storage Temperature Range | Connector Pins Air G | | -65 | +150 | С |
| TJ | Maximum Junction Temperature | kimum Junction Temperature | | | +150 | С |
| T∟ | Lead Temperature (Soldering, 10 seconds) | (V _{VDD} , V _{ICCx} , V _{HSD±} ,) Conta (V _{ICCx} to GND V _{HSD±} to GND Power to GND External Pins to GND (V _{HSD±} , V _{ICCx}) System Side Pin (V _{HSD±} , V _{OCCx} , S, /OE, | | | +260 | С |
| VVDD S VVICC V VSW V VOCC, VSW V VCONTROL C ICCSW C IUSBSW C IIK C TSTORAGE S TJ N TL I ESD H | IEC 61000-4-2 System ESD | Connector Pins | Air Gap | 15 | | kV |
| | | $(V_{VDD}, V_{ICCx}, V_{HSD\pm},)$ | Contact | -0.5 | | ΓV |
| | IEC 61000-4-5 Surge ESD | V _{ICCx} to GND | | -24 | 24 | V |
| | | $V_{\text{HSD}\pm}$ to GND | | -16 | 16 | V |
| | | Power to GND | | $\begin{array}{c ccccccccccccccccccccccccccccccccccc$ | | |
| ESD | Human Body Model, JEDEC JESD22-A114 | | C | | | |
| | | System Side Pin (V _{HSDx±} , V _{OCCx} , S, /OE, | | 2 | | kV |
| | Charged Device Model, JEDEC LESD22-C101 | All Pins | | -0.5 -0.5 -0.5 -0.5 -0.5 -0.5 -0.5 -65 -65 -65 -24 -16 4 -24 -16 | | |

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance. ON does not recommend exceeding them or designing to Absolute Maximum Ratings.

| Symbol | Parameter | Min. | Тур. | Max. | Unit |
|--------------------|----------------------------------|------|------|------------------|------|
| V _{VDD} | Supply Voltage | 2.7 | 4.2 | 5.5 | V |
| V _{ICC} | Type C Input Voltage | 0 | | 5.5 | V |
| Vocc | Type C Output Voltage | 0 | | 5.5 | V |
| Iccsw | Maximum CC Switch Current | | | 1 | А |
| V _{CNTRL} | Control Input Voltage (SEL, /OE) | -0.5 | | V _{VDD} | V |
| V _{SW} | HSD/USB Switch I/O Voltage | -0.5 | | 4.5 | V |
| TA | Operating Temperature | -40 | | +85 | С |

FUSB252 — Type C CC with D+\D- Port Protection Switch

DC Electrical Characteristics

Unless otherwise specified: Recommended T_A and T_J temperature ranges. All typical values are at $T_A=25^\circ\text{C}$ and $V_{DD}=4.2$ V unless otherwise specified.

| Symbol | Parameter | V _{DD} (V) | Conditions T | | T _A = -40 to +85°C T _J =-40 to +125°C | | Unit |
|------------------------------|---------------------------------|---------------------|--|------|---|------|------|
| | | 55() | | Min. | Тур. | Max. | |
| Basic Oper | ation Device | | | | | | |
| I | Quiescent Supply Current | 2 7 to 5 5 | /OE = L, I _{OUT} =0 | | 9 | | |
| Icc | Quiescent Supply Current | 2.7 to 5.5 | /OE = H I _{OUT} =0 | | 9 | | μA |
| I _{OFF} | Power-Off Leakage Current | 0 | | | 3 | | μA |
| Basic Oper | ation CC switch | | | - | | | |
| I _{SD(DB)} | Dead Battery Supply Current | 0 to UVLO | Dead Battery State Supply Current | | 15 | | uA |
| R _{ON} | CC Path On Resistance | 2.7 to 5.5 | I _{OUT} = 200 mA | | 350 | 480 | mΩ |
| V _{OV TRIP} | Input OVP Lockout | 2.7 to 5.5 | V _{ICC} Rising | | 5.65 | 6.20 | v |
| VOV_TRIP | | 2.7 10 5.5 | V _{ICC} Falling | | 5.3 | | v |
| $V_{\text{OV}_{\text{HYS}}}$ | Input OVP Hysteresis | 2.7 to 5.5 | | | 0.35 | | V |
| VUVLO | Under-Voltage Lockout | 2.7 to 5.5 | V _{DD} Rising | | 2.55 | 2.70 | v |
| 10120 | | | V _{DD} Falling | | 2.5 | | - |
| | | | Shutdown Threshold | | 150 | | |
| TSD | Thermal Shutdown ⁽¹⁾ | | Return from Shutdown | | 130 | | °C |
| | | | Hysteresis | | 20 | | |
| Pd | d Dead Battery Pull-Down | 0 to | Dead Battery Resistance | 4.08 | 5.10 | 6.12 | kΩ |
| Ru | Rd Resistance | | Voltage on Pin | 0.25 | | 2.6 | V |
| Basic Oper | ation HSD Switch | | | | | | |
| V _{OV_TRIP} | Input OVP Lockout | 2.7 to 5.5 | $V_{HSD\pm}$ Rising | | 4.4 | 5.0 | v |
| VOV_TRIP | | 2.7 10 0.0 | V _{HSD±} Falling | | T_J=-40 to +1 Iin. Typ. 9 9 9 3 15 350 5.65 5.3 0.35 2.55 2.55 2.55 150 130 20 0.08 .08 5.10 .25 - 4.4 4.1 0.3 -1.2 | | v |
| $V_{\text{OV}_{\text{HYS}}}$ | Input OVP Hysteresis | 2.7 to 5.5 | | | 0.3 | | V |
| $V_{\text{UV}_\text{TRIP}}$ | Input Under-Voltage Lockout | 2.7 to 5.5 | | | -1.2 | | V |
| V _{IH} | Input Voltage High | 2.7 to 5.5 | | 1.3 | | | V |
| V _{IL} | Input Voltage Low | 2.7 to 5.5 | | | | 0.5 | V |
| I _{IN} | Control Input Leakage | 2.7 to 5.5 | $V_{SW} = 0$ to V_{DD} | | 0.1 | | μA |
| | | 4.2 | 0≤HSDn ≤3.6 V | | 2 | | μA |
| l _{oz} | Off State Leakage | 4.2 | 0≤HSD1n _± , HSD2n _± ≤3.6 V | | 100 | | nA |
| R _{ON} | HS Switch On Resistance | 4.2 | V _{SW} = 0.4 V, I _{ON} = -8 mA | | 5 | | Ω |
| ΔR_{ON} | HS Delta R _{ON} | 4.2 | V _{SW} = 0.4 V, I _{ON} = -8 mA | | 0.1 | | Ω |

Note:

1. Guaranteed by characterization, not production tested

AC Electrical Characteristics

Unless otherwise specified: Recommended T_A and T_J temperature ranges. All typical values are at T_A =25°C and V_{DD} =3.8 V unless otherwise specified.

| Symbol | Parameter | V _{DD} (V) | Conditions | T _A = -40 to T _J =-40 to + | | Uni | |
|---------------------------|---|---------------------|--|---|------|------|---------|
| | | | | Min. | Тур. | Max. | |
| CC Switch | Timing Parameter | • | | l | | | |
| t _{OVP} | Response Time ⁽²⁾ | 2.7 to 5.5 | I_{OUT} = 0.2 A, C _L = 200 pF, V _{ICCx} 5 V to 6 V | | 0.5 | 1.0 | μs |
| t _{ON} | Turn-On Time | | VDD Rising 2 V to 3 V | | 25 | | ms |
| T _{MBB} | Make-Before-Break | 2.7 to 5.5 | VDD Rising 2 V to 3 V | | 600 | | ns |
| CC Switch | Capacitance | | | | | | • |
| Con | Switch Path On Capacitance ⁽²⁾ | 2.7 to 5.5 | | | 100 | | pF |
| CC Switch | Bandwidth | | | | | | |
| BW | PD Traffic Bandwidth ⁽²⁾ | 2.7 to 5.5 | R_L = 50 Ω , C_L = 200 pF | | 25 | | MHz |
| HSD Swite | h Timing Parameter | | | | | | |
| t _{OVP} | Response Time ⁽²⁾ | 2.7 to 5.5 | I_{OUT} = 0.2 A, V _{D±} 4 V to 5 V | | 0.5 | 1.0 | μs |
| t _{ON} | Turn-On Time, /OE to Output ⁽²⁾ | 2.7 to 5.5 | $\label{eq:relation} \begin{array}{l} R_{L} = 50 \ \Omega, \ C_{L} = 5 \ pF, \\ V_{SW} = 0.8 \ V \end{array}$ | | 25 | | ms |
| toff | Turn-Off Time, /OE to Output ⁽²⁾ | 2.7 to 5.5 | $\label{eq:relation} \begin{array}{l} R_{L} = 50 \ \Omega, \ C_{L} = 5 \ pF, \\ V_{SW} = 0.8 \ V \end{array}$ | | 100 | 400 | ns |
| t _{PD} | Propagation Delay ⁽²⁾ | 2.7 to 5.5 | R_L = 50 Ω , C_L = 5 pF, | | 0.25 | | ns |
| T _{BBM} | Break-Before-Make ⁽²⁾ | 2.7 to 5.5 | $R_L = 50 \Omega, C_L = 5 pF,$ $V_{SWx} = 0.8 V SEL= H <-> L$ | | 100 | | μs |
| O _{IRR} | Off Isolation | 2.7 to 5.5 | R _L = 50 Ω, f = 240 MHZ | | -25 | | dB |
| Xtalk | Non-Adjacent Channel Crosstalk | 2.7 to 5.5 | R _L = 50 Ω, f = 240 MHZ | | -40 | | dB |
| HSD Swite | h Capacitance | | | | | | |
| C _{IN} | Control Pin Input Capacitance ⁽²⁾ | 0 | | | 1.5 | | |
| C _{ON} | HSD+/HSD- On Capacitance ⁽²⁾ | 2.7 to 5.5 | /OE = L, f = 240 MHz, | | 4 | | pF |
| C_{OFF} | HSD1 _x , HSD2 _x Off Capacitance ⁽²⁾ | 2.7 to 5.5 | /OE = H | | 2.5 | | |
| USB Swite | h Bandwidth | | | | | | |
| BW | -3 db Bandwidth ⁽²⁾ | 2.7 to 5.5 | $R_L = 50 \Omega, C_L = 0 pF$ | | 1400 | | - MHz |
| DVV | | 2.7 to 5.5 | R_L = 50 Ω, C_L = 5 pF | | 560 | | 1011 12 |
| USB High- | Speed-Related | T | Γ | | | 1 | 1 |
| $t_{\text{SK}(\text{P})}$ | Skew of Opposite Transitions of the Same Output ⁽²⁾ | | $R_L = 50 \Omega, C_L = 5pF$ | | 25 | | ps |
| tJ | Total Jitter ⁽²⁾ | | $R_L = 50 \Omega$, $C_L = 5 pF$, $t_R = t_F = 500 ps (10-90\%) at$ 480 Mbps (PRBS=2 ¹⁵ – 1) | | 200 | | ps |

Note:

2. Guaranteed by characterization, not production tested.

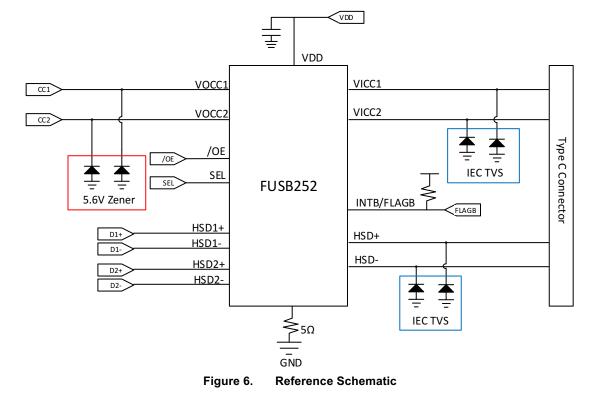
Operation and Application Description

Out of Spec Surge/Spike Voltage due to Hot Plug

The FUSB252 protects end systems against 20 V DC on the CC pin, in cases where the FUSB252 is tested to mimic a hot plug event, a fully charged cable connected to a power supply set to 20 V is used to zap the VICC pins of the device. In these cases, the inductance of the cable causes voltage spikes that are higher than the absolute maximum ratings of the of the VICC pins. These voltages can cause damage to the VOCC pins. This scenario does not occur in normal usage. The Type-C specification prevents the plug from having 20V on VBUS from a PD source prior to a PD contract being completed. When the 20 V potential is on VBUS and shorted to the CC pin, it causes a detach and the voltage spikes are less likely to occur. The following reference circuit is required when the application calls for additional protection to protect against such event as hot plug.

Application Specific Schematic

- Place a 5 V to 6 V rated Zener TVS diode such as (CZRF52C5V6 or CD1005-Z5V1) on the VOCC pin, and a 5 Ω resistor to device ground to prevent the FUSB252 from being damaged during these tests. With this additional protection if is also important to select the right external VICC IEC TVS for the best overall performance.
- Without the additional protection the device by itself can withstand up to 9 V under the same hot plug condition

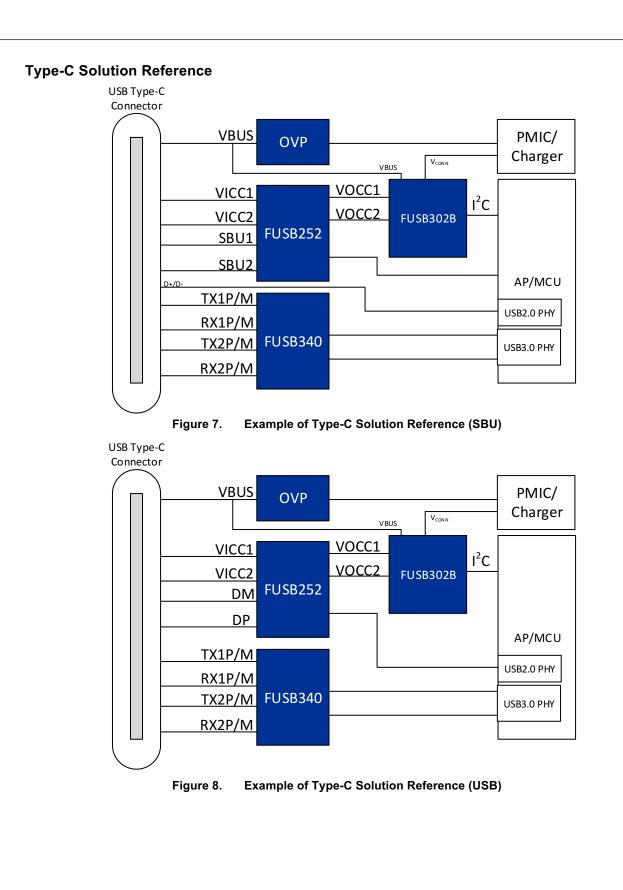


Over-Voltage Protection

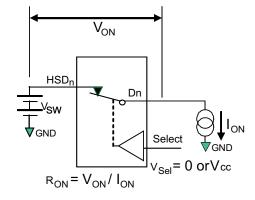
When over-voltage event is detected, device will activate OVP to shutdown the switch within t_{OVP} , as well as signal the FLAGB to indicate there is OV event to the system.

Fault Reporting

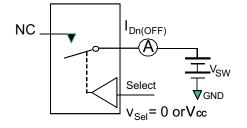
Upon the detection of an over-voltage event, the INTB/FLAGB signals the fault by activating LOW.



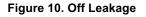
Test Diagrams

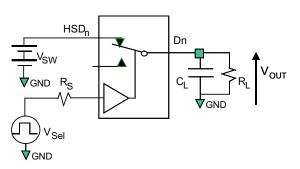




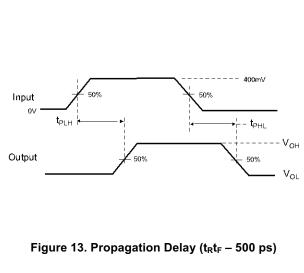


**Each switch port is tested separately

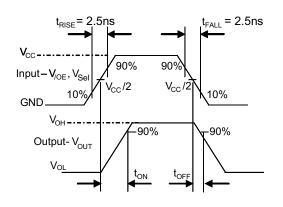


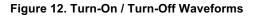


 R_L , R_S , and C_L are functions of the application environment (see AC Tables for specific values) C_L includes test fixture and stray capacitance.









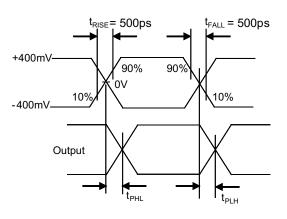
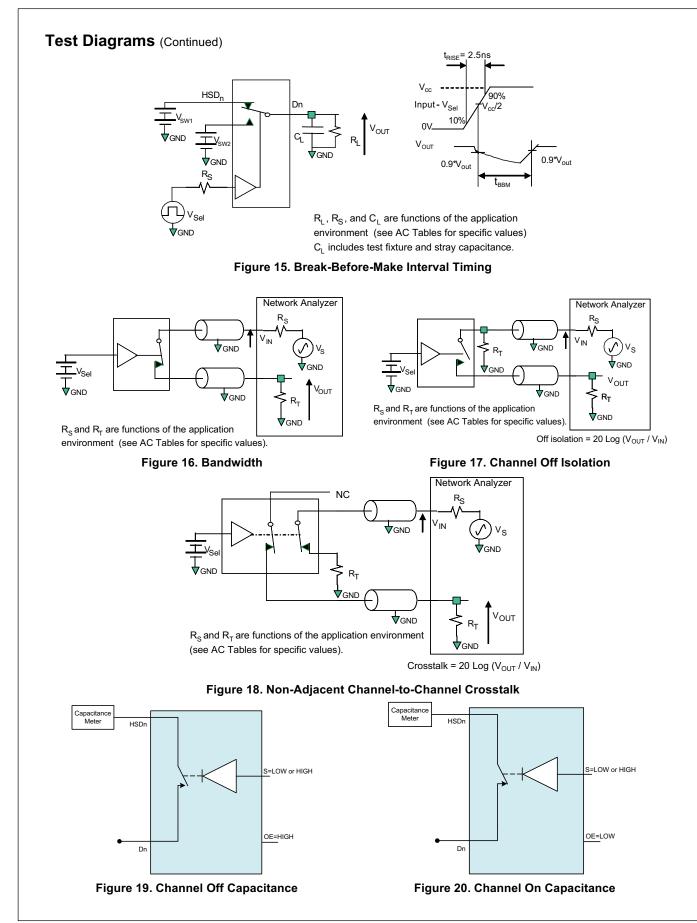
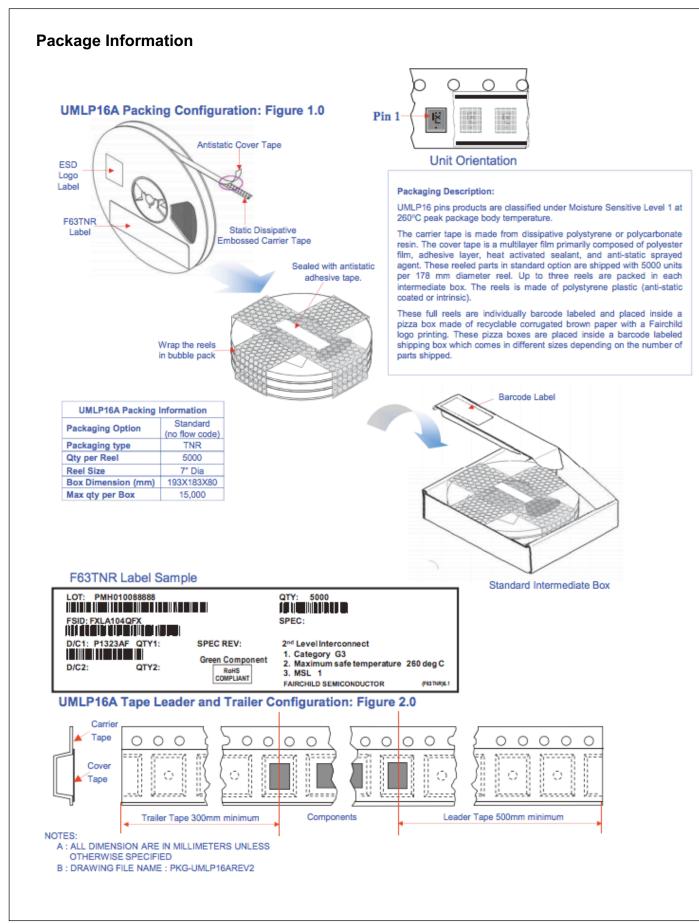
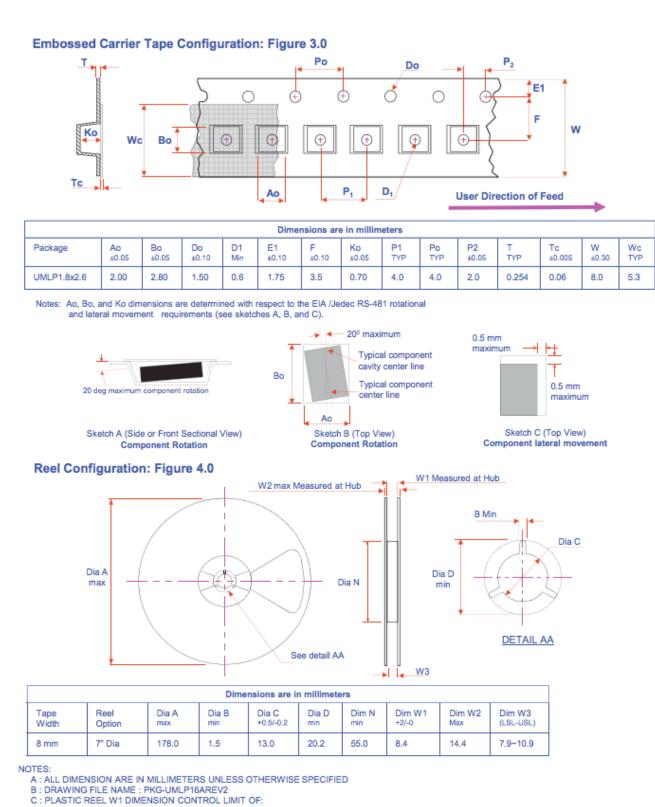


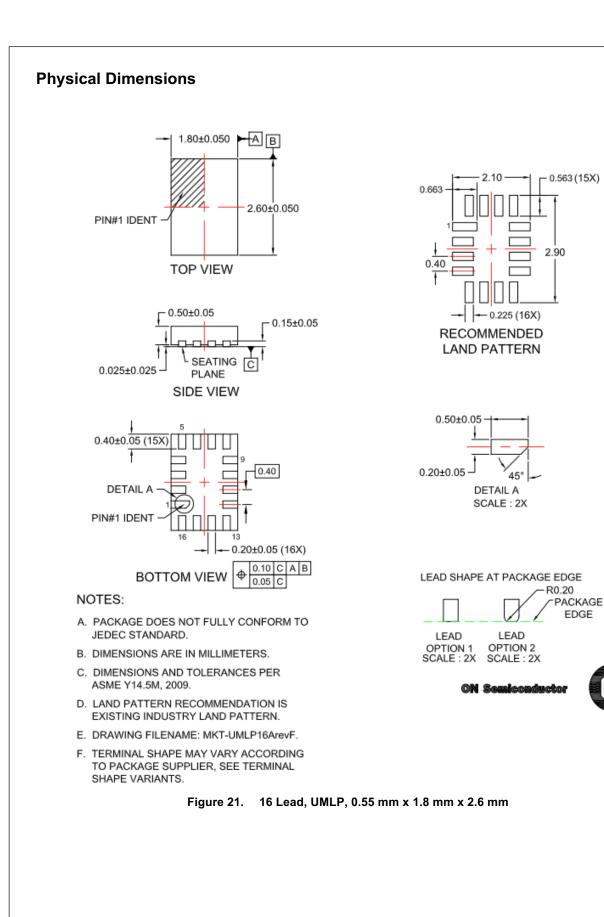
Figure 14. Intra-Pair Skew Test t_{SK(P)}







⁸MM REEL=±1.0MM AND 12MM REEL AND ABOVE =±1.5MM



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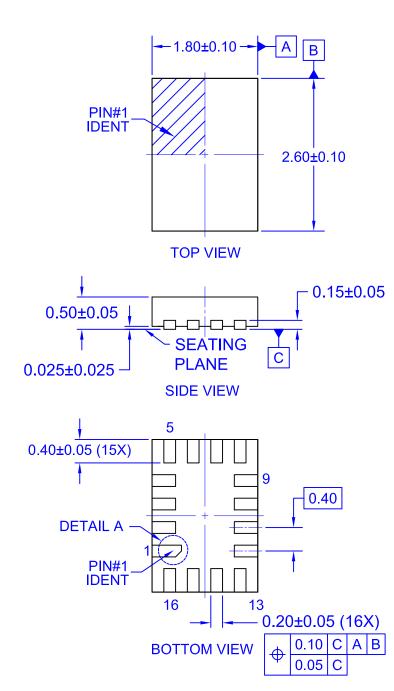
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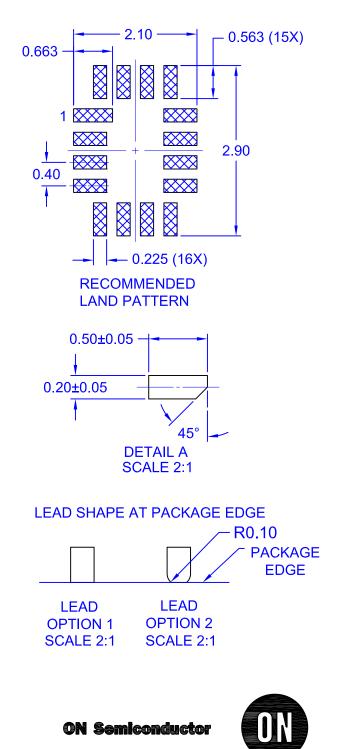
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